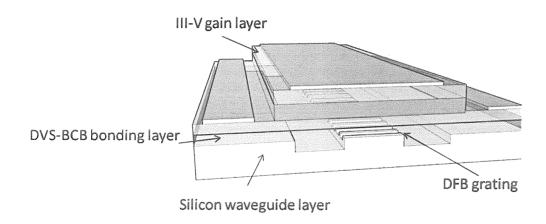
Hybrid III-V/Silicon laser based on DVS-BCB die-to-wafer bonding

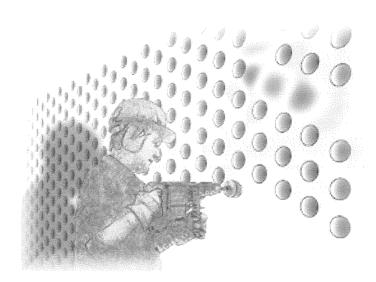
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Abstract: Recently reported state-of-the-art hybrid III-V/Silicon laser diodes are fabricated using molecular die-to-wafer bonding, which imposes strict requirements regarding the smoothness, cleanliness and quality of the III-V surface to be bonded. By the use of an adhesive DVS-BCB intermediate layer to bond the III-V dies on top of the SOI waveguide circuits, these surface quality requirements become far less strict, providing a possibility for a fabrication procedure that can be suitable for the industrial-scale production. The aim of this work is to demonstrate a continuous wave hybrid III-V/Silicon Fabry-Perot laser diode capable of operating at elevated temperatures. Also, the additional objective of this work is to develop a multiple die-to-wafer bonding procedure, suitable for large scale industrial production, and to assess its robustness with respect to the laser parameters (threshold current, external efficiency, thermal behavior). In the end, it is our aim to design and fabricate a distributed feedback laser diode (DFB) based on the developed DVS-BCB bonding procedure in order to demonstrate suitability of this technique in the realization of an array of single wavelength lasers.





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- 1. V-Groove approach for inverted taper coupling in silicon photonics: J. V. Galán
 - 2. Experimental Study of the Non-Linear Dynamics of Quantum-Dot InAs/InGaAsP/InP (100) Twin-Stripe Lasers Emitting at 1.5µm: Jose Pozo
 - 3. InGaAs-InAlGaAs Monolithically Integrated Temporal Phase Coded OCDMA Encoder/Decoder: S. McMaster
 - 4. A spectrally resolved study of quantum dot lasers: G.A.P. Thé
 - 5. Carrier Transport Effects in Multi Layer Quantum Dot Lasers: M. Rossetti
 - 6. Membrane couplers for optical interconnections on CMOS ICs: A. Morant
 - 7. Optical Losses in Photonic Crystal Waveguides, Induced by Contact Strips for Electrical Pumping: Peter Kaspar
 - 8. Measuring the Time-of-Flight with an optical MEMS-modulator: Joris Roels
 - 9. InP-membrane based photodetector for optical interconnections on Si: P.R.A. Binetti
 - 10. High bandwidth InP-based 1.55 µm waveguide photodetector fabricated in an amplifier layer stack with active-passive integration: L. Xu
 - 11. Design and simulation of movable micromirrors on silicon substrate: Comanescu Florin Constantin
- ♣ 12. Fabrication of polymer-based devices using nanoimprint technology, Jie Teng
 - 13. Liquid crystal technology for wavelength tuning in SOI structures: Wout De Cort
 - 14 Photonic Reservoir Computing: interconnected Semiconductor Optical Amplifiers: Kristof Vandoorne
 - 15. Wayequide grating photonic system analysis for sensor applications: Roxana Ileana Rebigan
 - 16. Design Of A Monolithically Integrated All-Optical Label Swapper For Spectral Amplitude Code Labels Using Cross-Gain Modulation: Christian Habib
 - 17. Combined Technologies: Photolithography and Electron Beam Lithography for RF Filters on GaN Development: Herghelegiu Alexandru
 - 18. Deep dry-etched single-mode narrow waveguide for all-optical switches with InGaAs/AlAsSb quantum wells: Ping Ma
 - 19. Assessment of mesh-interconnected integrated photonic switch circuits: Aaron Albores Meija
 - 20. SOI-based couplers for the transition from DPSK- to DQPSK-demodulators: Karsten Voigt
 - 21. Adjustment of birefringence on Silicon-on-Insulator (SOI) by mechanical bending: Georg Winzer
 - 22. Analysis of thermal crosstalk between DFB-laserdiodes on SOI: B. Wohlfeil
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 - 24. Bragg Gratings on SOI Rib Waveguides A Comparison of Different Geometries: Ivano Giuntoni
 - 25. Slow Light in Chalcogenide Photonic Crystals: Marcel Spurny

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- 26. A comparative study of compact electro-optic modulators based on 1D corrugated waveguide surrounded by Silicon dioxide: Antoine Brimont
- 27. Design and Fabrication of Apodised Crows on Silicon Nitride: J.D. Domenech
- 28. Silicon optical modulator: Fenggiao Dong
- 29. Large Integration Scale Circuits in SiON Technology: Carlo Ferrari
- 30. SOI photonic wires-based devices: sidewall roughness-induced losses and characterization: Antonio Canciamilla
- 31. InP Photonic Crystals bonded to SOI wires: Yacine Halioua & Tim Karle
- 32. Fabrication of photonic integrated circuits using high resolution CMOS fabrication process: Shankar Kumar Selvaraja
- 33. Silicon compatible laser based on colloidal quantum dots: Bram De Geyter
- 34. Al2O3:Er waveguide amplifiers for Si-technology compatible integrated optical applications: L. Agazzi
- 35. Label-free nanophotonic biosensors in silicon based on slot waveguides: Tom Claes
- 36. Design of an integrated electo-optically tunable filter for tunable laser purposes: B.W. Tilma
- 37. Sol-Gel Ormosil-on-Silicon Microphotonics: Paulo Moreira
- 38. 10 Gb/s All-Optical Non-Inverted 1x4 Multi-Wavelength Conversion in a 1.55 μm QD-SOA: J. Herrera
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 - 47. Towards optimizing photonic crystal cavities for Quantum Dot coupling: Khaled Mnaymneh
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 - 49. Multi-waveguide based collector array for the detection of backscattered light from highly scattering media: N. Ismail
 - 50. Continuous wave InGaAsP/InP Fabry-Perot lasers on silicon: Tiphaine Dupont